RENESAS

3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O, BUS-HOLD

74LVCH32245A

FEATURES:

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- · Supports hot insertion
- · Available in 96-ball LFBGA package

DRIVE FEATURES:

- Balanced Output Drivers: ±24mA
- Reduced system switching noise

APPLICATIONS:

H3

2DIR

2A1

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

FUNCTIONAL BLOCK DIAGRAM

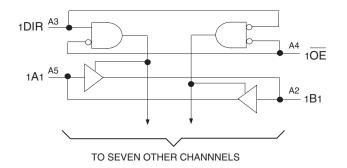
DESCRIPTION:

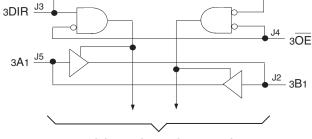
This 32-bit bus transceiver is built using advanced dual metal CMOS technology. This high-speed, low power transceiver is ideal for asynchronous communication between two busses (A and B). The Direction and Output Enable controls are designed to operate the device as either four independent 8-bit transceivers or one 32-bit transceiver. The direction control pins (DIR) control the direction of data flow. The output enable pins (OE) override the direction control and disable both ports. All inputs are designed with hysteresis for improved noise margin.

All pins can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

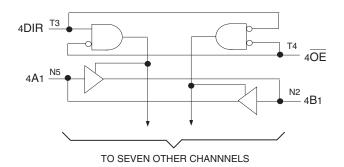
The LVCH32245A has been designed with a \pm 24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance

The LVCH32245A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.









TO SEVEN OTHER CHANNNELS

INDUSTRIAL TEMPERATURE RANGE



H4 20F

E2 2B1

PIN CONFIGURATION

Г

6	1 A 2	1 A 4	1 A 6	1 A 8	2 A 2	2 A 4	2 A 6	2 A 7	3 A 2	3 A 4	3 A 6	3 A 8	4 A 2	4 A 4	4 A 6	4 A 7
5	1 A 1	1 A 3	1 A 5	1 A 7	2 A 1	2 A 3	2 A 5	2 A 8	3 A 1	зАз	3 A 5	3 A 7	4 A 1	4 A 3	4 A 5	4 A 8
4	10E	GND	Vcc	GND	GND	Vcc	GND	20E	зŌЕ	GND	Vcc	GND	GND	Vcc	GND	40E
3	1DIR	GND	Vcc	GND	GND	Vcc	GND	2DIR	зDIR	GND	Vcc	GND	GND	Vcc	GND	4DIR
2	1B1	1B3	1B5	1B7	2B1	2B3	2B5	2B8	3B1	зВз	3B5	3B7	4B1	4B3	4B5	4B8
1	1B2	1B4	1B6	1B8	2B2	2B4	2B6	2B7	3B2	3B4	3B6	3B8	4B2	4B4	4B6	4B7
	A	В	С	D	E	F	G	Н	J	ĸ	L	М	N	Р	R	Т

LFBGA TOPVIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
TSTG	Storage Temperature	–65 to +150	°C
Ιουτ	DC Output Current	–50 to +50	mA
Ік Іок	Continuous Clamp Current, VI < 0 or VO < 0	-50	mA
ICC ISS	Continuous Current through each Vcc or GND	±100	mA

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	pF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description	
XOE	DE Output Enable Input (Active LOW)	
xDIR	Direction Control Input	
xAx	Side A Inputs or 3-State Outputs ⁽¹⁾	
хВх	Side B Inputs or 3-State Outputs ⁽¹⁾	

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE(1)

Inp	outs	
xOE	xDIR	Outputs
L	L	Bus B data to Bus A
L	Н	Bus A data to Bus B
н х		Z

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level X = Don't Care

Z = High Impedance

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Co	nditions	Min.	Typ. ⁽²⁾	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3V	VI = 2V	-75	—	_	μA
IBHL			VI = 0.8V	75	—	_	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	VI = 1.7V	—	—	_	μA
IBHL			VI = 0.7V	_	_	_	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	—	_	±500	μA
Ibhlo							

NOTES:

1. Pins with Bus-Hold are identified in the pin description.

2. Typical values are at Vcc = 3.3V, +25°C ambient.



DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Te	st Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	-	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	—	0.8	
Iн IiL	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	-	-	±5	μA
Іоzн	High Impedance Output Current	Vcc = 3.6V	Vo = 0 to 5.5V	_	_	±10	μA
lozl	(3-State Output pins)						
IOFF	Input/Output Power Off Leakage	Vcc = 0V, VIN or Vo \leq 5	5V	_	_	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA	l	_	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL ICCH	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or Vcc	-	-	10	μA
lccz		$3.6 \le VIN \le 5.5V^{(2)}$			-	10	
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V,	other inputs at Vcc or GND	-	_	500	μA

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	TestC	onditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Іон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Іон = – 6mA	2	_	
		Vcc = 2.3V	Іон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V		2.4	_	1
		Vcc = 3V	Iон = - 24mA	2.2	_	1
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IOL = 6mA	—	0.4	
			IOL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3V	IOL = 24mA	_	0.55	

NOTE:

 VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.



OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	76	pF
Cpd	Power Dissipation Capacitance per Transceiver Outputs disabled		8	

SWITCHING CHARACTERISTICS⁽¹⁾

		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	1.5	4.7	1	4	ns
tPHL	xAx to xBx, xBx to xAx					
tРZH	Output Enable Time	1.5	6.7	1.5	5.5	ns
tPZL	xOE to xAx or xBx					
tPHZ	Output Disable Time	1.5	7.1	1.5	6.6	ns
tPLZ	xOE to xAx or xBx					
tРZH	Output Enable Time	1.5	7	1.5	5.5	ns
tPZL	xDIR to xAx or xBx					
tPHZ	Output Disable Time	1.5	7.4	1.5	6.6	ns
tPLZ	xDIR to xAx or xBx					
tsk(o)	Output Skew ⁽²⁾	_	_	_	500	ps

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to + 85°C.

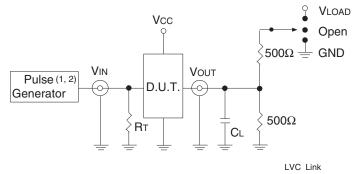
2. Skew between any two outputs of the same package and switching in the same direction.

74LVCH32245A 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽¹⁾ =2.7V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vт	1.5	1.5	Vcc/2	V
Vlz	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

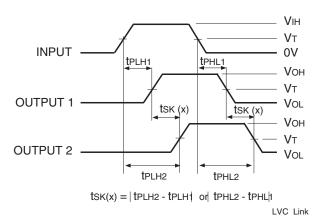
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns. 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

	<u> </u>
Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open

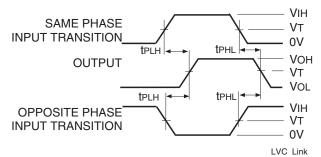


Output Skew - tsk(x)

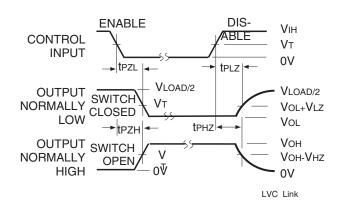
NOTES:

1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



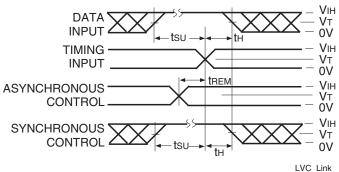
Propagation Delay



Enable and Disable Times

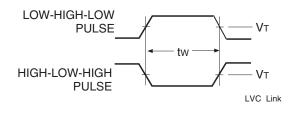
NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



Set-up, Hold, and Release Times

LVC LINK

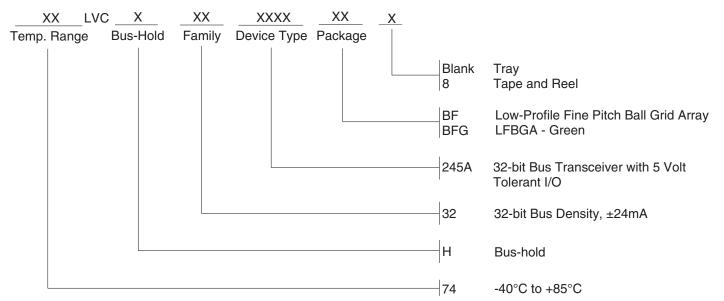


Pulse Width



74LVCH32245A 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

ORDERING INFORMATION



Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
А	74LVCH32245ABF	BF96	CABGA	I
	74LVCH32245ABF8	BF96	CABGA	I
	74LVCH32245ABFG	BFG96	CABGA	I
	74LVCH32245ABFG8	BFG96	CABGA	I

Datasheet Document History

02/29/2016Pg. 7Updated the ordering information by adding Tape and Reel.04/01/2021Pg. 1-7Rebranded as a Renesas datasheet. Added new table of orderable part information.



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